

RH1078M
 Micropower, Dual, Single-Supply
 Precision Op Amp

DIE CROSS REFERENCE

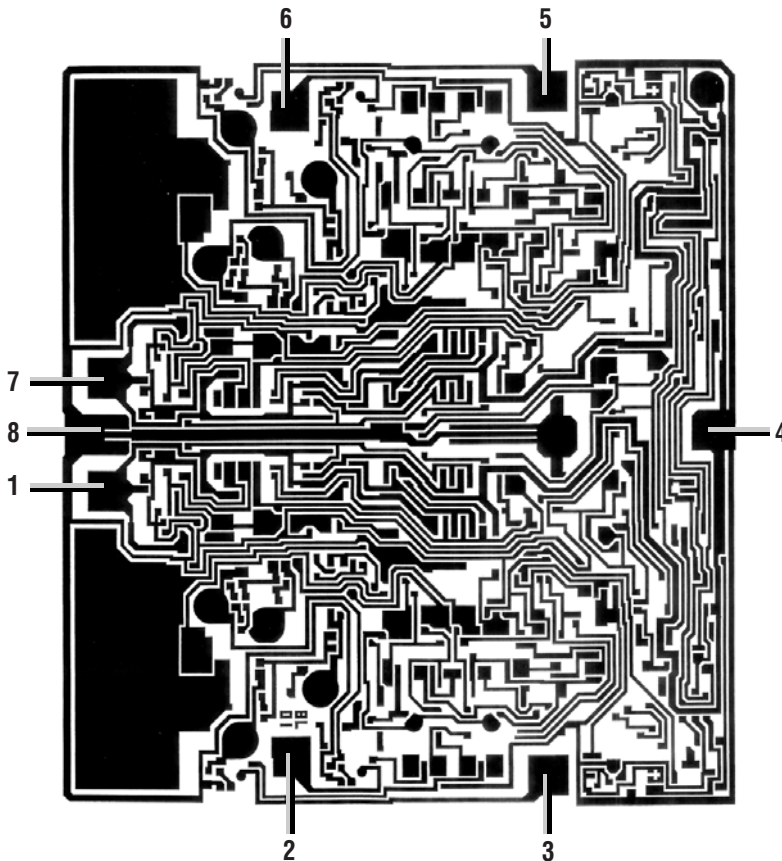
LTC Finished Part Number	Order DICE CANDIDATE Part Number
RH1078M	RH1078M DICE

Please refer to LTC standard product data sheet for other applicable product information.

PAD FUNCTION

1. OUTA
2. -INA
3. +INA
4. -V
5. +INB
6. -INB
7. OUTB
8. +V

12mils thick,
 backside (substrate) is an alloyed
 gold layer. Connect backside to V-.



90 × 97 mils

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DICE ELECTRICAL TEST LIMITS

$T_A = 25^\circ\text{C}$, $V_S = 5\text{V}$, $V_{CM} = 0.1\text{V}$, $V_{OUT} = 1.4\text{V}$, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS
V_{OS}	Input Offset Voltage			120	μV
I_{OS}	Input Offset Current			0.8	nA
I_B	Input Bias Current			15	nA
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0\text{V to } 3.5\text{V}$ $V_{CM} = 0.05\text{V to } 3.2\text{V}$	94		dB dB
PSRR	Power Supply Rejection Ratio	$V_S = 2.3\text{V to } 12\text{V}$ $V_S = 3.1\text{V to } 12\text{V}$	100		dB dB

DICE SPECIFICATION

RH1078M

DICE ELECTRICAL TEST LIMITS $T_A = 25^\circ\text{C}$, $V_S = 5\text{V}$, $V_{CM} = 0.1\text{V}$, $V_{OUT} = 1.4\text{V}$, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS
A_{VOL}	Large-Signal Voltage Gain	$V_O = 0.03\text{V}$ to 4V, No Load	150		V/mV
		$V_O = 0.03\text{V}$ to 3.5V, $R_L = 50\text{k}$	120		V/mV
		$V_O = 0.05\text{V}$ to 4V, No Load			V/mV
		$V_O = 0.05\text{V}$ to 3.5V, $R_L = 50\text{k}$			V/mV
V_{OUT}	Output Voltage Swing	Output Low, No Load		6	mV
		Output Low, 2k to GND		2	mV
		Output Low, $I_{SINK} = 100\mu\text{A}$		130	mV
		Output High, No Load	4.2		V
		Output High, 2k to GND	3.5		V
SR	Slew Rate	$A_V = 1$, $V_S = \pm 2.5\text{V}$	0.04	75	V/ μs
I_S	Supply Current	Per Amplifier		2.3	μA
	Minimum Supply Voltage	Note 2		350	V

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS
V_{OS}	Input Offset Voltage			350	μV
I_{OS}	Input Offset Current			0.8	nA
I_B	Input Bias Current			15	nA
	Input Voltage Range		13.5 -15.0		V V
CMRR	Common Mode Rejection Ratio	$V_{CM} = 13.5\text{V}$, -15V	97		dB
		$V_{CM} = 13\text{V}$, -14.9V			dB
PSRR	Power Supply Rejection Ratio	$V_S = 5\text{V}$, 0V to $\pm 18\text{V}$	100		dB
A_{VOL}	Large-Signal Voltage Gain	$V_O = \pm 10\text{V}$, $R_L = 50\text{k}$	1000		V/mV
		$V_O = \pm 10\text{V}$, $R_L = 2\text{k}$	300		V/mV
		$V_O = \pm 10\text{V}$, $R_L = 5\text{k}$			V/mV
V_{OUT}	Output Voltage Swing	$R_L = 50\text{k}$	± 13		V
		$R_L = 2\text{k}$	± 11		V
		$R_L = 5\text{k}$			V
SR	Slew Rate		0.06		V/ μs
I_S	Supply Current	Per Amplifier		100	μA

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: Power supply rejection ratio is measured at the minimum supply voltage.

Wafer level testing is performed per the indicated specifications for dice. Considerable differences in performance can often be observed for dice versus packaged units due to the influences of packaging and assembly on certain devices and/or parameters. Please consult factory for more information on dice performance and lot qualifications via lot sampling test procedures.

Dice data sheet subject to change. Please consult factory for current revision in production.